

10-MHz LOW-NOISE LOW-VOLTAGE LOW-POWER OPERATIONAL AMPLIFIERS

Check for Samples: [LMV721](#), [LMV722](#)

FEATURES

- **Power-Supply Voltage Range:** 2.2 V to 5.5 V
- **Low Supply Current:** 930 μ A/Amplifier at 2.2 V
- **High Unity-Gain Bandwidth:** 10 MHz
- **Rail-to-Rail Output Swing**
 - 600- Ω Load: 120 mV From Either Rail at 2.2 V
 - 2-k Ω Load: 50 mV From Either Rail at 2.2 V
- **Input Common-Mode Voltage Range Includes Ground**
- **Input Voltage Noise:** 9 nV/ $\sqrt{\text{Hz}}$ at f = 1 kHz

APPLICATIONS

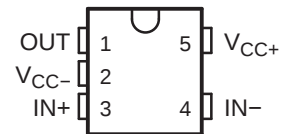
- Cellular and Cordless Phones
- Active Filter and Buffers
- Laptops and PDAs
- Battery Powered Electronics

DESCRIPTION/ORDERING INFORMATION

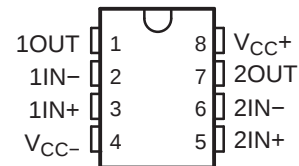
The LMV721 (single) and LMV722 (dual) are low-noise low-voltage low-power operational amplifiers that can be designed into a wide range of applications. The LMV721 and LMV722 have a unity-gain bandwidth of 10 MHz, a slew rate of 5 V/ μ s, and a quiescent current of 930 μ A/amplifier at 2.2 V.

The LMV721 and LMV722 are designed to provide optimal performance in low-voltage and low-noise systems. They provide rail-to-rail output swing into heavy loads. The input common-mode voltage range includes ground, and the maximum input offset voltage are 3.5 mV (over recommended temperature range) for the devices. Their capacitive load capability is also good at low supply voltages. The operating range is from 2.2 V to 5.5 V.

LMV721...DBV or DCK PACKAGE
(TOP VIEW)



LMV722...D, DGK, OR DRG PACKAGE
(TOP VIEW)



ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER		TOP-SIDE MARKING ⁽³⁾
–40°C to 105°C	Single	SC-70 – DCK	Reel of 3000	LMV721IDCKR	RK_
			Reel of 250	LMV721IDCKT	
		SOT-23 – DBV	Reel of 3000	LMV721IDBVR	RBF_
	Dual	SOIC – D	Reel of 2500	LMV722IDR	MV722I
			Tube of 75	LMV722ID	
		VSSOP – DGK	Reel of 2500	LMV722IDGKR	R6_
		QFN – DRG	Reel of 2500	LMV722IDRGR	ZYY

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

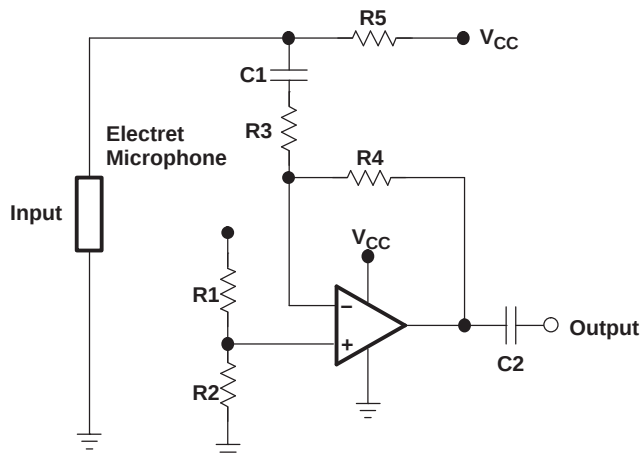
(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(3) DBV/DCK/DGK: The actual top-side marking has one additional character that designates the wafer fab/assembly site.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Typical Application



Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage ⁽²⁾		6	V
V_{ID}	Differential input voltage ⁽³⁾	$\pm$ Supply voltage		V
θ_{JA}	Package thermal impedance ⁽⁴⁾	D package ⁽⁵⁾		97
		DBV package ⁽⁵⁾		206
		DCK package ⁽⁵⁾		252
		DGK package ⁽⁵⁾		172
		DRG package ⁽⁶⁾		50.7
T_J	Operating virtual-junction temperature		150	°C
T_{stg}	Storage temperature range	-65	150	°C

- (1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values (except differential voltages and V_{CC} specified for the measurement of I_{OS}) are with respect to the network GND.
- (3) Differential voltages are at $IN+$ with respect to $IN-$.
- (4) Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (5) The package thermal impedance is calculated in accordance with JESD 51-7.
- (6) The package thermal impedance is calculated in accordance with JESD 51-5.

Recommended Operating Conditions

		MIN	MAX	UNIT
$V_{CC+} - V_{CC-}$	Supply voltage	2.2	5.5	V
T_J	Operating virtual-junction temperature	-40	105	°C

ESD Protection

	TYP	UNIT
Human-Body Model	2000	V
Machine Model	100	V

Electrical Characteristics

 $V_{CC+} = 2.2\text{ V}$, $V_{CC-} = \text{GND}$, $V_{ICR} = V_{CC+}/2$, $V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T_J	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage		25°C		0.02	3	mV
			–40°C to 105°C			3.5	
TCV_{IO}	Input offset voltage average drift		25°C		0.6		$\mu\text{V}/^\circ\text{C}$
I_{IB}	Input bias current		25°C		260		nA
I_{IO}	Input offset current		25°C		25		nA
CMRR	Common-mode rejection ratio	$V_{ICR} = 0\text{ V to }1.3\text{ V}$	25°C	70	88		dB
			–40°C to 105°C	64			
PSRR	Power-supply rejection ratio	$V_{CC+} = 2.2\text{ V to }5\text{ V}$, $V_O = 0$, $V_{ICR} = 0$	25°C	80	90		dB
			–40°C to 105°C	70			
V_{ICR}	Input common-mode voltage	CMRR $\geq 50\text{ dB}$	25°C		–0.3		V
					1.3		
A_{VD}	Large-signal voltage gain	$R_L = 600\ \Omega$, $V_O = 0.75\text{ V to }2\text{ V}$	25°C	75	81		dB
			–40°C to 105°C	70			
		$R_L = 2\text{ k}\Omega$, $V_O = 0.5\text{ V to }2.1\text{ V}$	25°C	75	84		
			–40°C to 105°C	70			
V_O	Output swing	$R_L = 600\ \Omega\text{ to }V_{CC+}/2$	25°C	2.090	2.125		V
			–40°C to 105°C	2.065			
			25°C		0.071	0.120	
			–40°C to 105°C			0.145	
		$R_L = 2\text{ k}\Omega\text{ to }V_{CC+}/2$	25°C	2.150	2.177		
			–40°C to 105°C	2.125			
			25°C		0.056	0.080	
			–40°C to 105°C			0.105	
I_O	Output current	Sourcing, $V_O = 0\text{ V}$, $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	10	14.9		mA
			–40°C to 105°C	5			
		Sinking, $V_O = 2.2\text{ V}$, $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	10	17.6		
			–40°C to 105°C	5			
I_{CC}	Supply current	LMV721	25°C		0.93	1.3	mA
			–40°C to 105°C			1.5	
		LMV722	25°C		1.81	2.4	
			–40°C to 105°C			2.6	
SR	Slew rate ⁽¹⁾		25°C		4.9		V/ μs
GBW	Gain bandwidth product		25°C		10		MHz
Φ_m	Phase margin		25°C		67.4		°
G_m	Gain margin		25°C		–9.8		dB
V_n	Input-referred voltage noise	$f = 1\text{ kHz}$	25°C		9		$\text{nV}/\sqrt{\text{Hz}}$
I_n	Input-referred current noise	$f = 1\text{ kHz}$	25°C		0.3		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$, $A_V = 1$, $R_L = 600\ \Omega$, $V_O = 500\text{ mV}_{pp}$	25°C		0.004		%

(1) Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

Electrical Characteristics

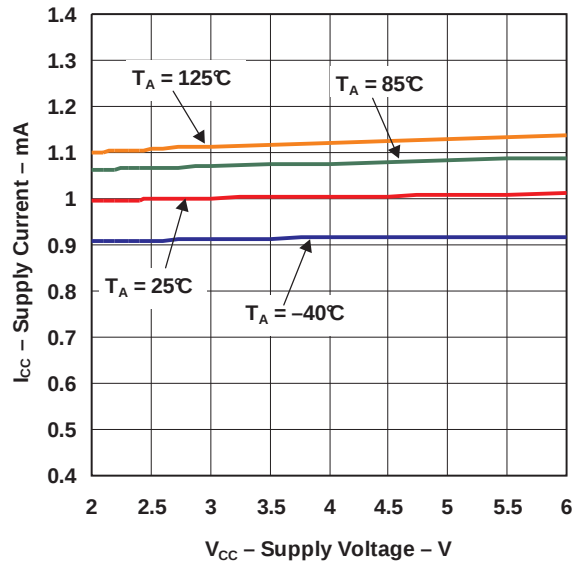
$V_{CC+} = 5\text{ V}$, $V_{CC-} = \text{GND}$, $V_{ICR} = V_{CC+}/2$, $V_O = V_{CC+}/2$, and $R_L > 1\text{ M}\Omega$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	T_J	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage		25°C	-0.08		3	mV
			-40°C to 105°C			3.5	
TCV_{IO}	Input offset voltage average drift		25°C		0.6		$\mu\text{V}/^\circ\text{C}$
I_{IB}	Input bias current		25°C		260		nA
I_{IO}	Input offset current		25°C		25		nA
CMMR	Common-mode rejection ratio	$V_{ICR} = 0\text{ V to }4.1\text{ V}$	25°C	80	89		dB
			-40°C to 105°C	75			
PSRR	Power-supply rejection ratio	$V_{CC+} = 2.2\text{ V to }5\text{ V}$, $V_O = 0$, $V_{ICR} = 0$	25°C	70	90		dB
			-40°C to 105°C	64			
V_{ICR}	Input common-mode voltage	CMRR $\geq 50\text{ dB}$	25°C		-0.3		V
					4.1		
A_{VD}	Large-signal voltage gain	$R_L = 600\ \Omega$, $V_O = 0.75\text{ V to }4.8\text{ V}$	25°C	80	87		dB
			-40°C to 105°C	70			
		$R_L = 2\text{ k}\Omega$, $V_O = 0.7\text{ V to }4.9\text{ V}$	25°C	80	94		
			-40°C to 105°C	70			
V_O	Output swing	$R_L = 600\ \Omega\text{ to }V_{CC+}/2$	25°C	4.84	4.882		V
			-40°C to 105°C	4.815			
			25°C		0.134	0.19	
			-40°C to 105°C			0.215	
		$R_L = 2\text{ k}\Omega\text{ to }V_{CC+}/2$	25°C	4.93	4.952		
			-40°C to 105°C	4.905			
			25°C		0.076	0.11	
			-40°C to 105°C			0.135	
I_O	Output current	Sourcing, $V_O = 0\text{ V}$, $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	20	52.6		mA
			-40°C to 105°C	12			
		Sinking, $V_O = 2.2\text{ V}$, $V_{IN(\text{diff})} = \pm 0.5\text{ V}$	25°C	15	23.7		
			-40°C to 105°C	8.5			
I_{CC}	Supply current	LMV721	25°C		1.03	1.4	mA
			-40°C to 105°C			1.7	
		LMV722	25°C		2.01	2.4	
			-40°C to 105°C			2.8	
SR	Slew rate ⁽¹⁾		25°C		5.25		V/ μs
GBW	Gain bandwidth product		25°C		10		MHz
Φ_m	Phase margin		25°C		72		°
G_m	Gain margin		25°C		-11		dB
V_n	Input-referred voltage noise	$f = 1\text{ kHz}$	25°C		8.5		$\text{nV}/\sqrt{\text{Hz}}$
I_n	Input-referred current noise	$f = 1\text{ kHz}$	25°C		0.2		$\text{pA}/\sqrt{\text{Hz}}$
THD	Total harmonic distortion	$f = 1\text{ kHz}$, $A_V = 1$, $R_L = 600\ \Omega$, $V_O = 500\text{ mV}_{pp}$	25°C		0.001		%

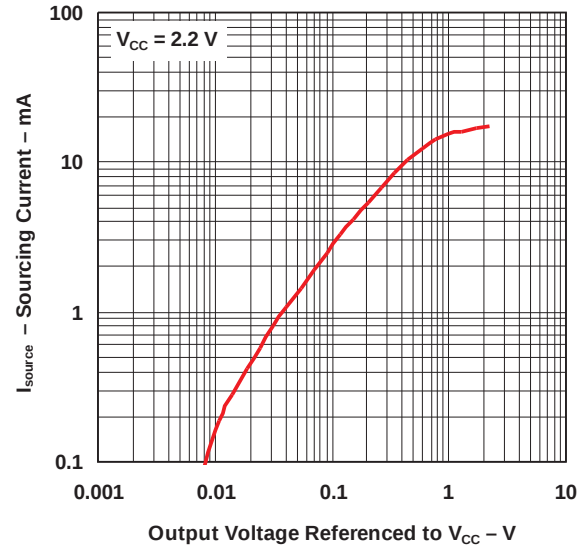
(1) Connected as voltage follower with 1-V step input. Number specified is the slower of the positive and negative slew rate.

TYPICAL CHARACTERISTICS

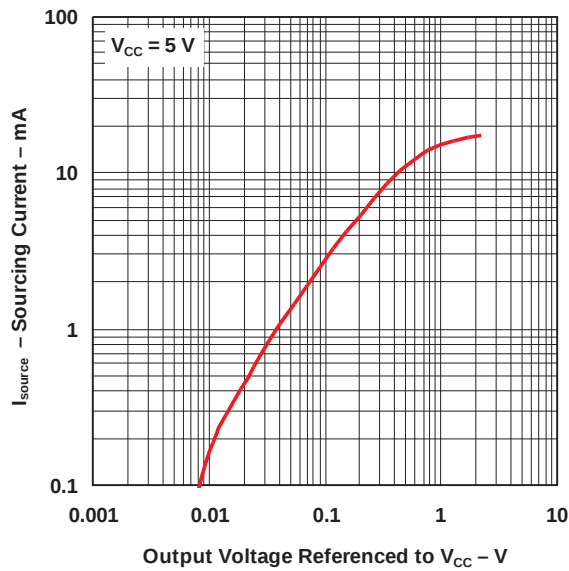
SUPPLY CURRENT
vs
SUPPLY VOLTAGE



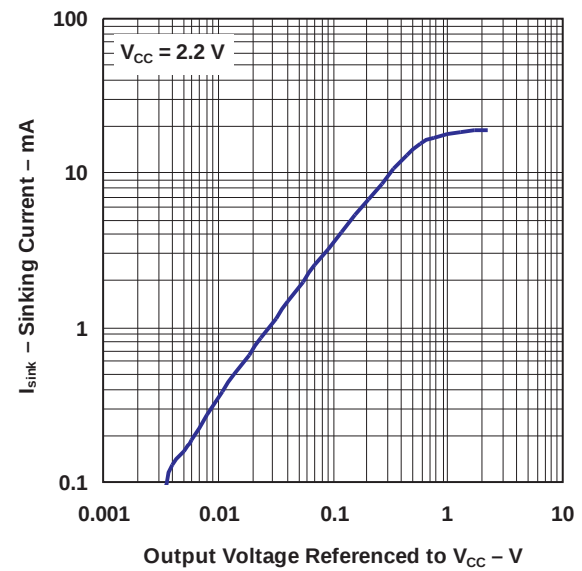
SOURCING CURRENT
vs
OUTPUT VOLTAGE



SOURCING CURRENT
vs
OUTPUT VOLTAGE

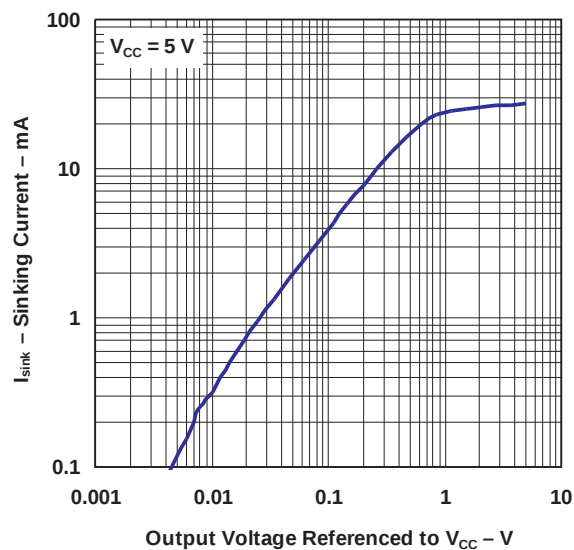


SINKING CURRENT
vs
OUTPUT VOLTAGE

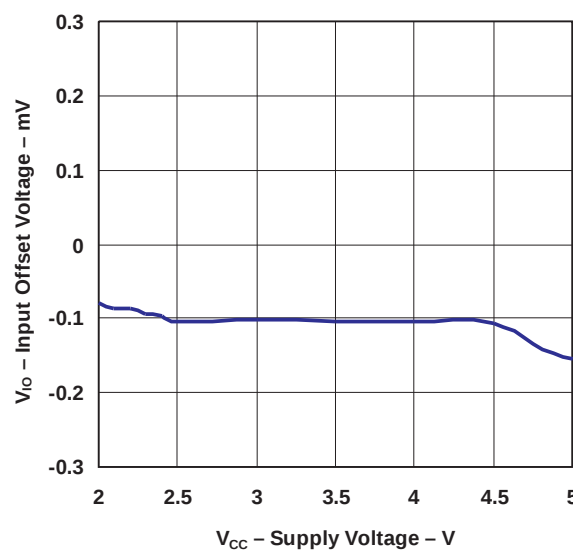


TYPICAL CHARACTERISTICS (continued)

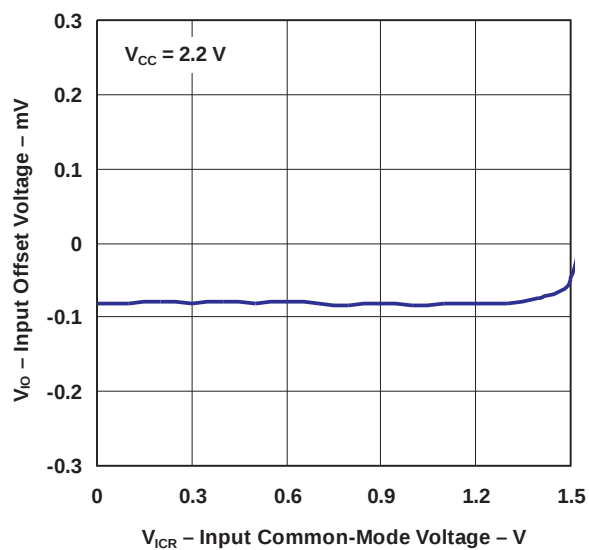
SINKING CURRENT
vs
OUTPUT VOLTAGE



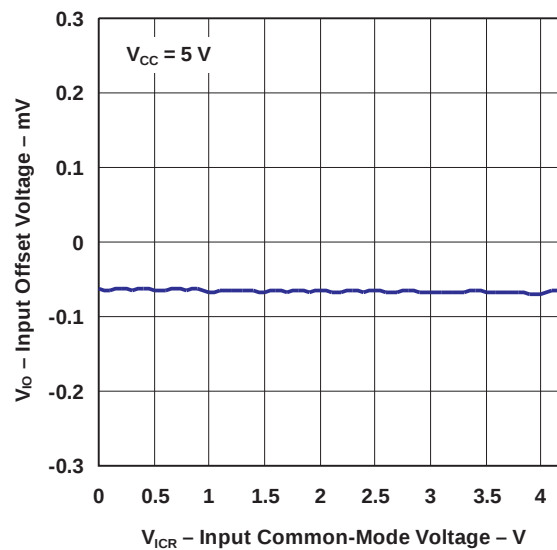
OUTPUT VOLTAGE SWING
vs
SUPPLY VOLTAGE



INPUT OFFSET VOLTAGE
vs
INPUT COMMON-MODE VOLTAGE

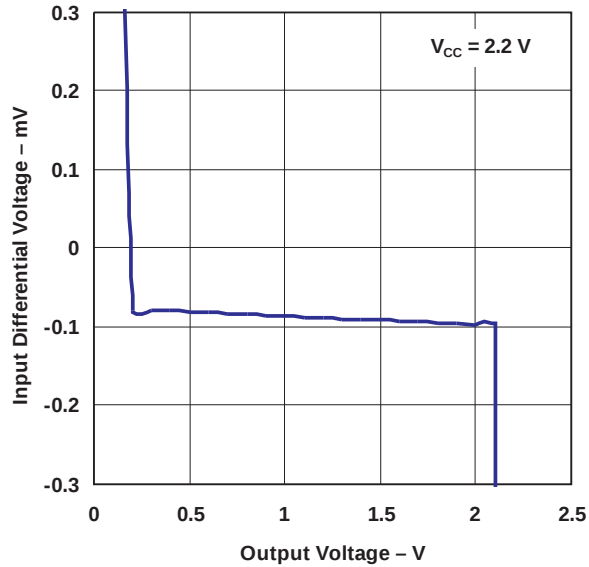


INPUT OFFSET VOLTAGE
vs
INPUT COMMON-MODE VOLTAGE

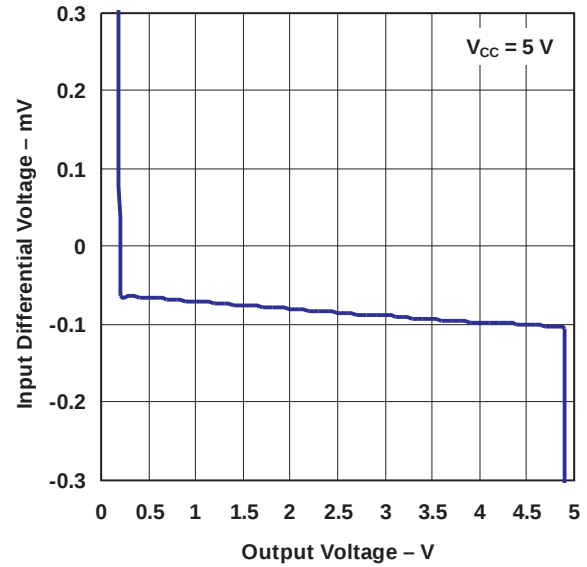


TYPICAL CHARACTERISTICS (continued)

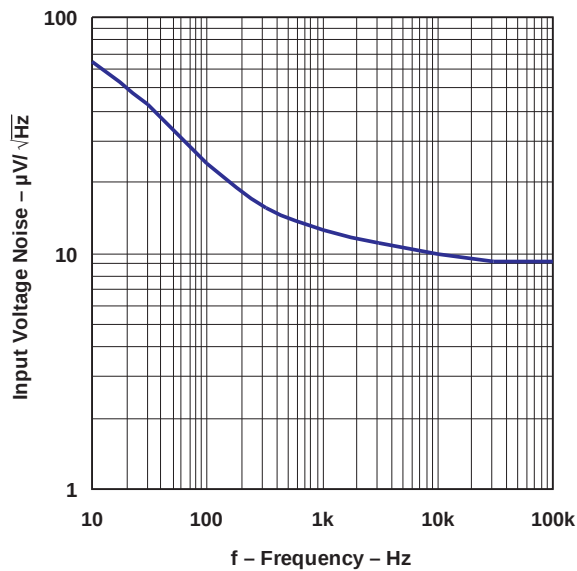
INPUT VOLTAGE
vs
OUTPUT VOLTAGE



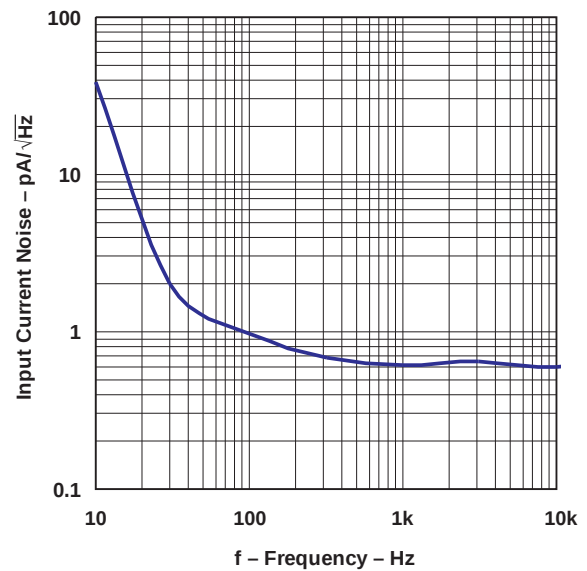
INPUT VOLTAGE
vs
OUTPUT VOLTAGE



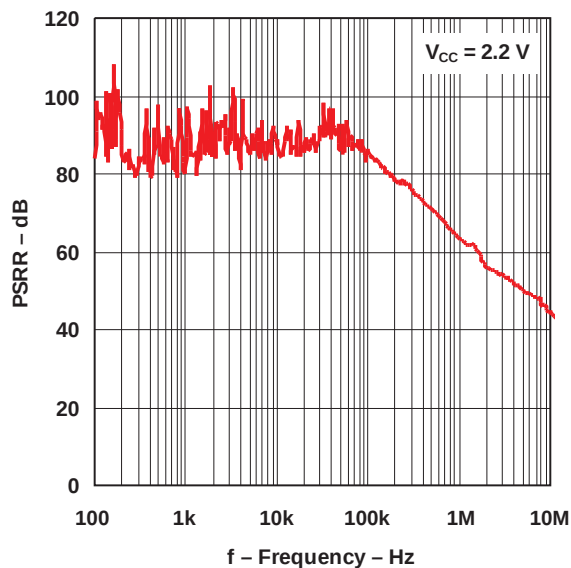
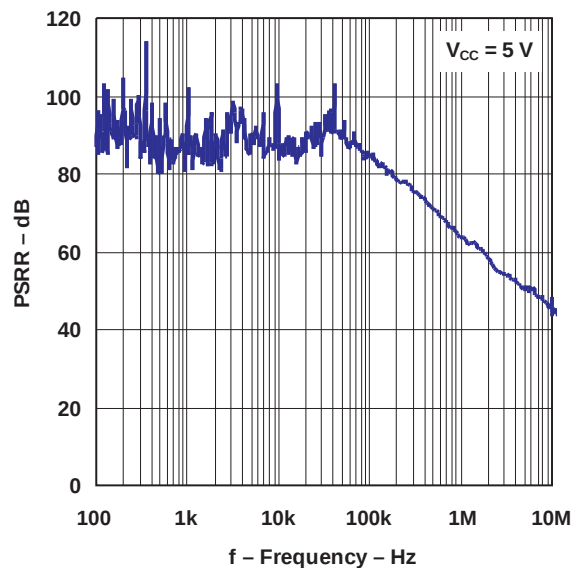
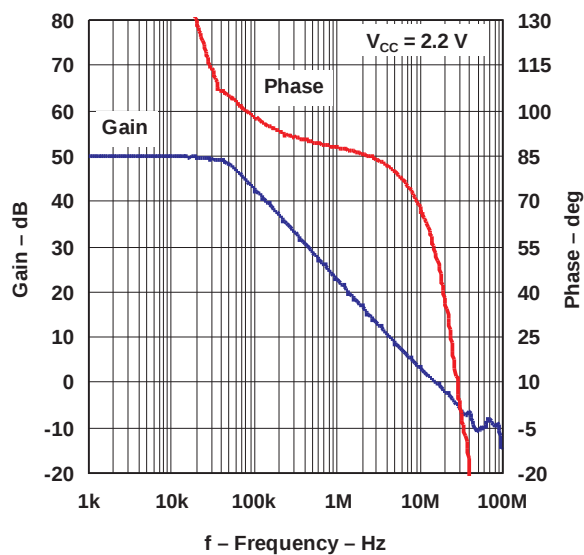
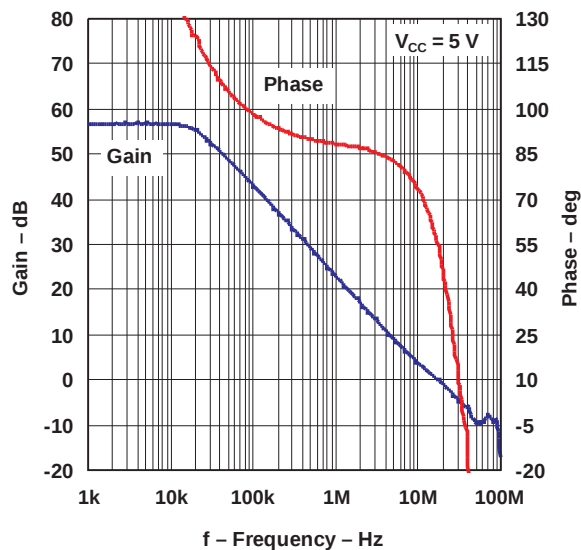
INPUT VOLTAGE NOISE
vs
FREQUENCY



INPUT CURRENT NOISE
vs
FREQUENCY

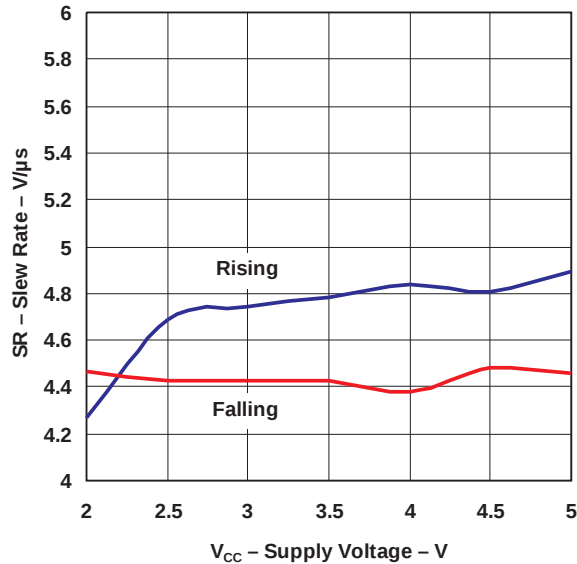


TYPICAL CHARACTERISTICS (continued)

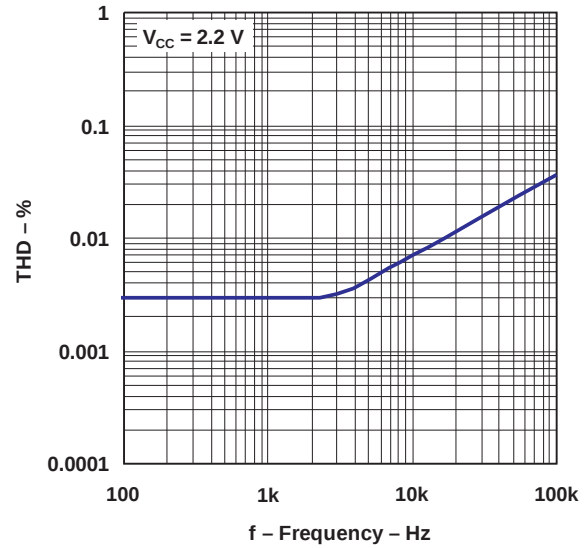
PSRR
vs
FREQUENCYPSRR
vs
FREQUENCYGAIN AND PHASE
vs
FREQUENCYGAIN AND PHASE
vs
FREQUENCY

TYPICAL CHARACTERISTICS (continued)

**SLEW RATE
vs
SUPPLY VOLTAGE**

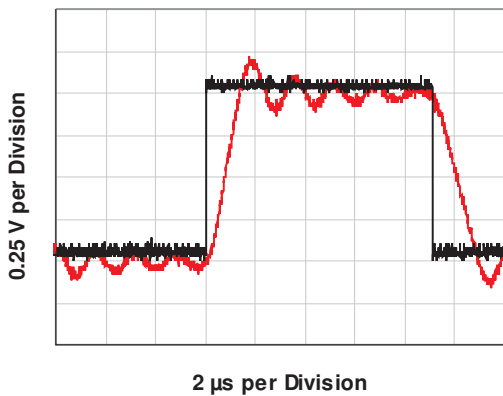


**THD
vs
FREQUENCY**



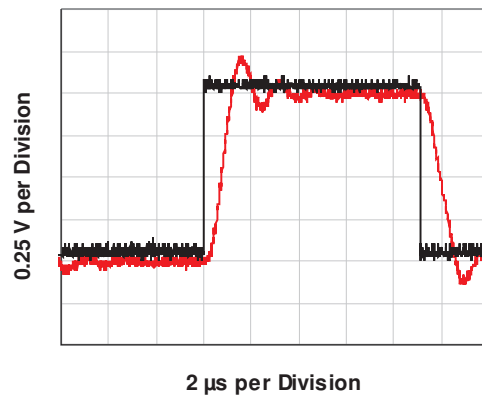
PULSE RESPONSE

V_{CC} = 5 V, R_L = 2 kΩ, C_L = 21.2 nF, R_O = 0 Ω



PULSE RESPONSE

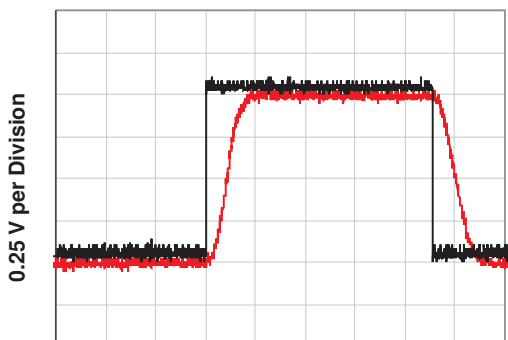
V_{CC} = 5 V, R_L = 2 kΩ, C_L = 21.2 nF, R_O = 2.1 Ω



TYPICAL CHARACTERISTICS (continued)

PULSE RESPONSE

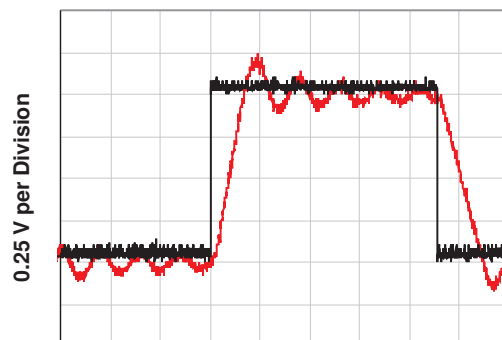
$$V_{CC} = 5\text{ V}, R_L = 2\text{ k}\Omega, C_L = 21.2\text{ nF}, R_o = 9.5\text{ }\Omega$$



2 μ s per Division

PULSE RESPONSE

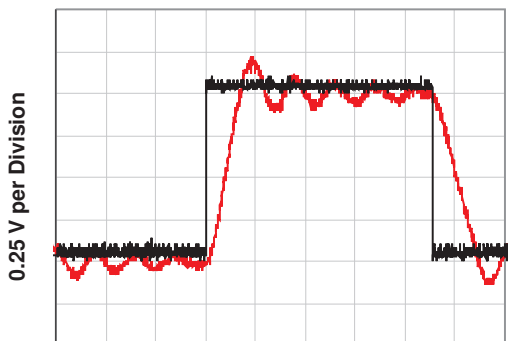
$$V_{CC} = 5\text{ V}, R_L = 10\text{ k}\Omega, C_L = 21.2\text{ nF}, R_o = 0\text{ }\Omega$$



2 μ s per Division

PULSE RESPONSE

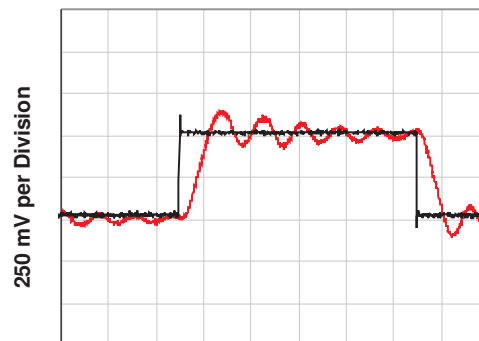
$$V_{CC} = 5\text{ V}, R_L = 600\text{ }\Omega, C_L = 21.2\text{ nF}, R_o = 0\text{ }\Omega$$



2 μ s per Division

PULSE RESPONSE

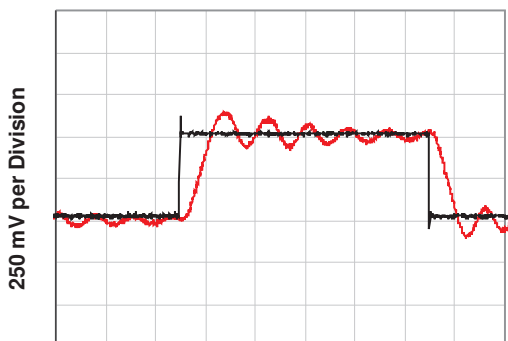
$$V_{CC} = 2.2\text{ V}, R_L = 2\text{ }\Omega, C_L = 2.12\text{ nF}, R_o = 0\text{ }\Omega$$



1 μ s per Division

PULSE RESPONSE

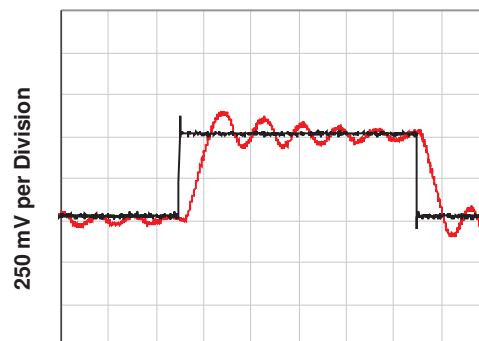
$$V_{CC} = 2.2\text{ V}, R_L = 2\text{ k}\Omega, C_L = 2.12\text{ nF}, R_o = 0\text{ }\Omega$$



1 μ s per Division

PULSE RESPONSE

$$V_{CC} = 2.2\text{ V}, R_L = 10\text{ k}\Omega, C_L = 2.12\text{ nF}, R_o = 0\text{ }\Omega$$

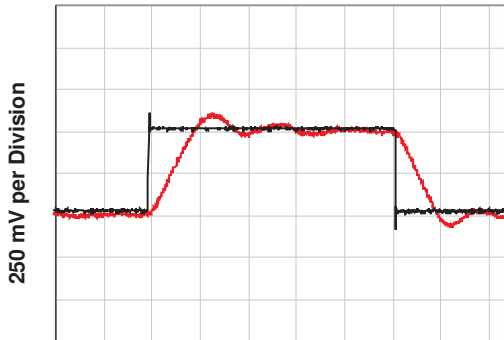


1 μ s per Division

TYPICAL CHARACTERISTICS (continued)

PULSE RESPONSE

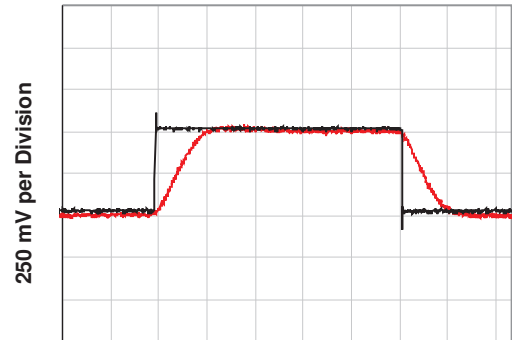
$V_{CC} = 2.2\text{ V}$, $R_L = 10\text{ k}\Omega$, $C_L = 2.12\text{ nF}$, $R_o = 2.2\text{ }\Omega$



1 μs per Division

PULSE RESPONSE

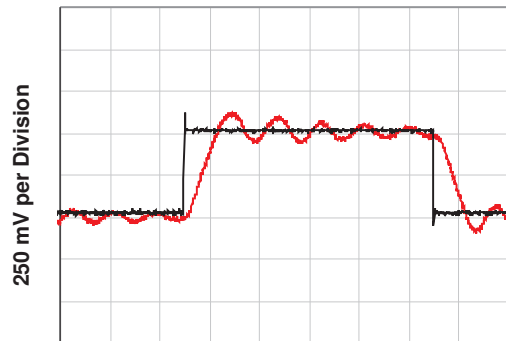
$V_{CC} = 2.2\text{ V}$, $R_L = 10\text{ k}\Omega$, $C_L = 2.12\text{ nF}$, $R_o = 11.5\text{ }\Omega$



1 μs per Division

PULSE RESPONSE

$V_{CC} = 2.2\text{ V}$, $R_L = 600\text{ }\Omega$, $C_L = 1.89\text{ nF}$, $R_o = 0\text{ }\Omega$



1 μs per Division

REVISION HISTORY

Changes from Revision B (August 2010) to Revision C	Page
• Changed all temperature parameters from max of 85°C to 105°C	1
• Changed supply voltage max value to 6 in Absolute Maximum Ratings table	2
• Changed supply voltage MAX value to 5.5 in Recommended Operating Conditions table	2
• Changed A_{VD} , V_O test conditons for $R_L = 600\ \Omega$: 0.75 V to 4.8 V	4
• Changed A_{VD} , V_O test conditons for $R_L = 2\ k\Omega$: 0.75 V to 4.8 V	4

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
LMV721IDBVR	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(RBFA, RBFM)
LMV721IDBVR.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	(RBFA, RBFM)
LMV721IDBVRG4	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	RBFM
LMV721IDBVRG4.A	Active	Production	SOT-23 (DBV) 5	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	RBFM
LMV721IDCKR	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	NIPDAU SN NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
LMV721IDCKR.A	Active	Production	SC70 (DCK) 5	3000 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
LMV721IDCKT	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAU NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
LMV721IDCKT.A	Active	Production	SC70 (DCK) 5	250 SMALL T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 105	(RKA, RKM)
LMV722ID	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I
LMV722ID.A	Active	Production	SOIC (D) 8	75 TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I
LMV722IDGKR	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	R6E
LMV722IDGKR.A	Active	Production	VSSOP (DGK) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	R6E
LMV722IDR	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I
LMV722IDR.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 105	MV722I

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "-" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF LMV722 :

- Automotive : [LMV722-Q1](#)

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV721IDBVR	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
LMV721IDBVRG4	SOT-23	DBV	5	3000	178.0	9.0	3.23	3.17	1.37	4.0	8.0	Q3
LMV721IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
LMV721IDCKR	SC70	DCK	5	3000	178.0	8.4	2.25	2.45	1.2	4.0	8.0	Q3
LMV721IDCKT	SC70	DCK	5	250	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3
LMV721IDCKT	SC70	DCK	5	250	180.0	8.4	2.47	2.3	1.25	4.0	8.0	Q3
LMV722IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.3	1.3	8.0	12.0	Q1
LMV722IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

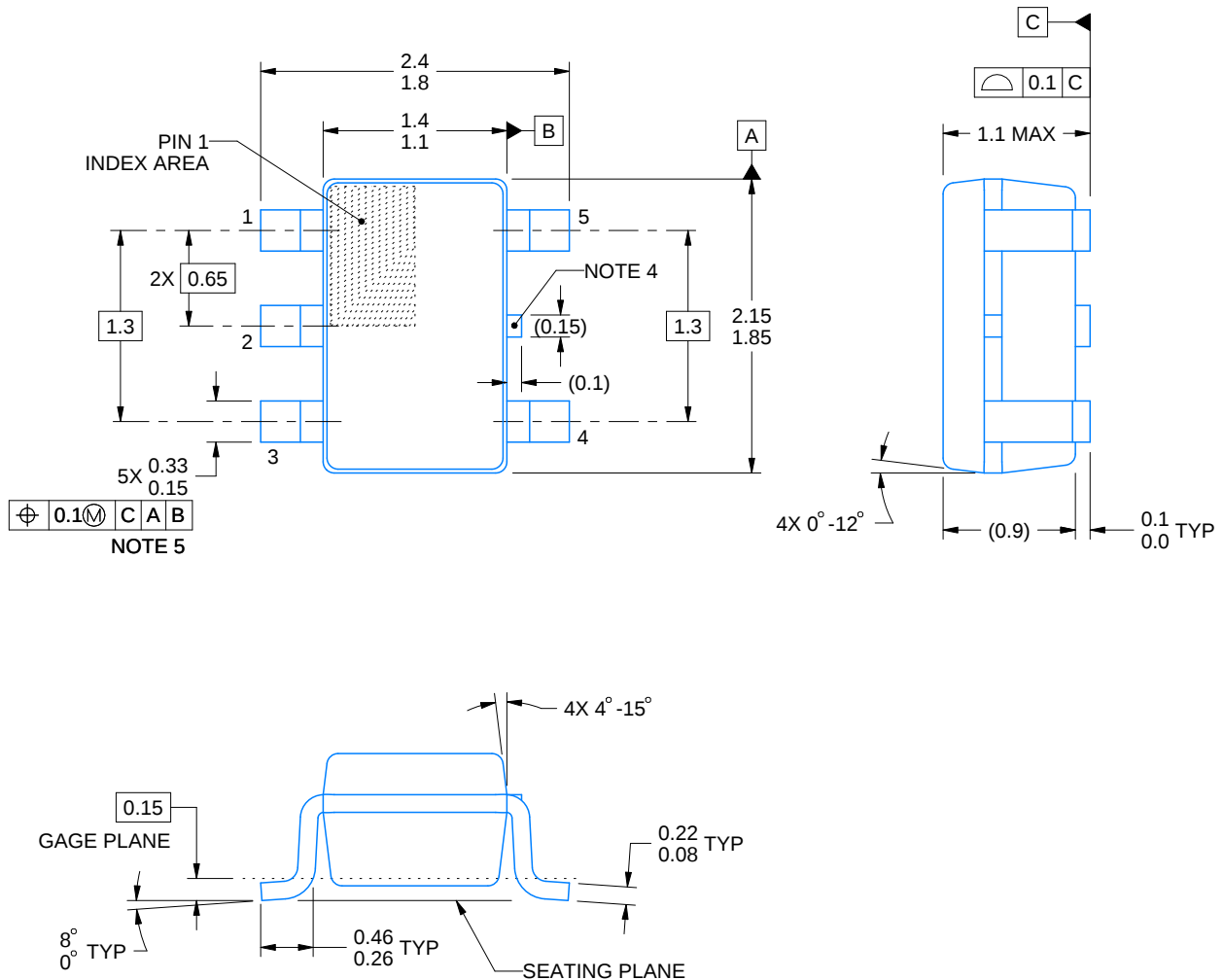
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV721IDBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
LMV721IDBVRG4	SOT-23	DBV	5	3000	180.0	180.0	18.0
LMV721IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
LMV721IDCKR	SC70	DCK	5	3000	208.0	191.0	35.0
LMV721IDCKT	SC70	DCK	5	250	180.0	180.0	18.0
LMV721IDCKT	SC70	DCK	5	250	202.0	201.0	28.0
LMV722IDGKR	VSSOP	DGK	8	2500	346.0	346.0	35.0
LMV722IDR	SOIC	D	8	2500	353.0	353.0	32.0

TUBE



*All dimensions are nominal

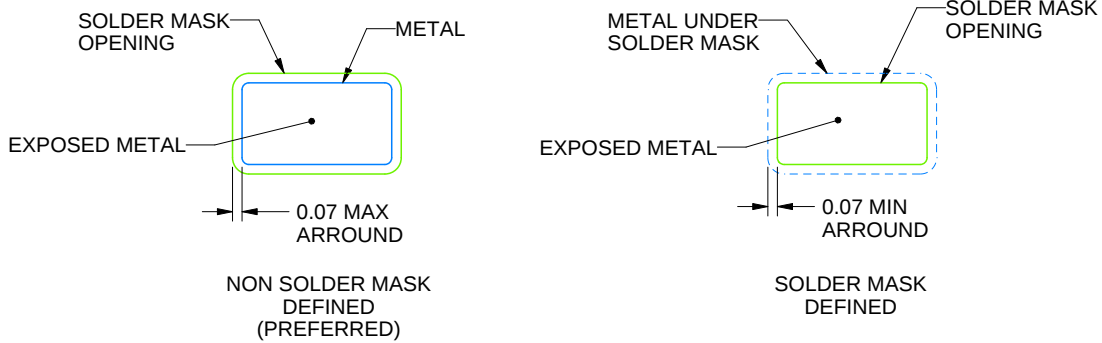
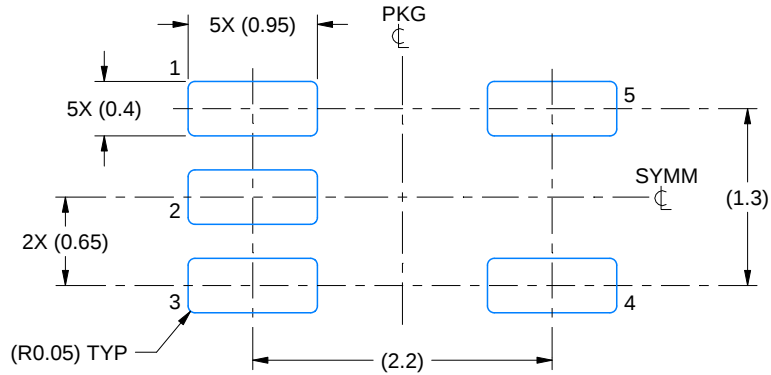
Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (μm)	B (mm)
LMV722ID	D	SOIC	8	75	507	8	3940	4.32
LMV722ID.A	D	SOIC	8	75	507	8	3940	4.32



4214834/G 11/2024

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



4214834/G 11/2024

NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
 BASED ON 0.125 THICK STENCIL
 SCALE:18X

4214834/G 11/2024

NOTES: (continued)

9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-178.
4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
5. Support pin may differ or may not be present.

EXAMPLE BOARD LAYOUT

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:15X



SOLDER MASK DETAILS

4214839/K 08/2024

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



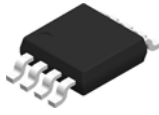
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:15X

4214839/K 08/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

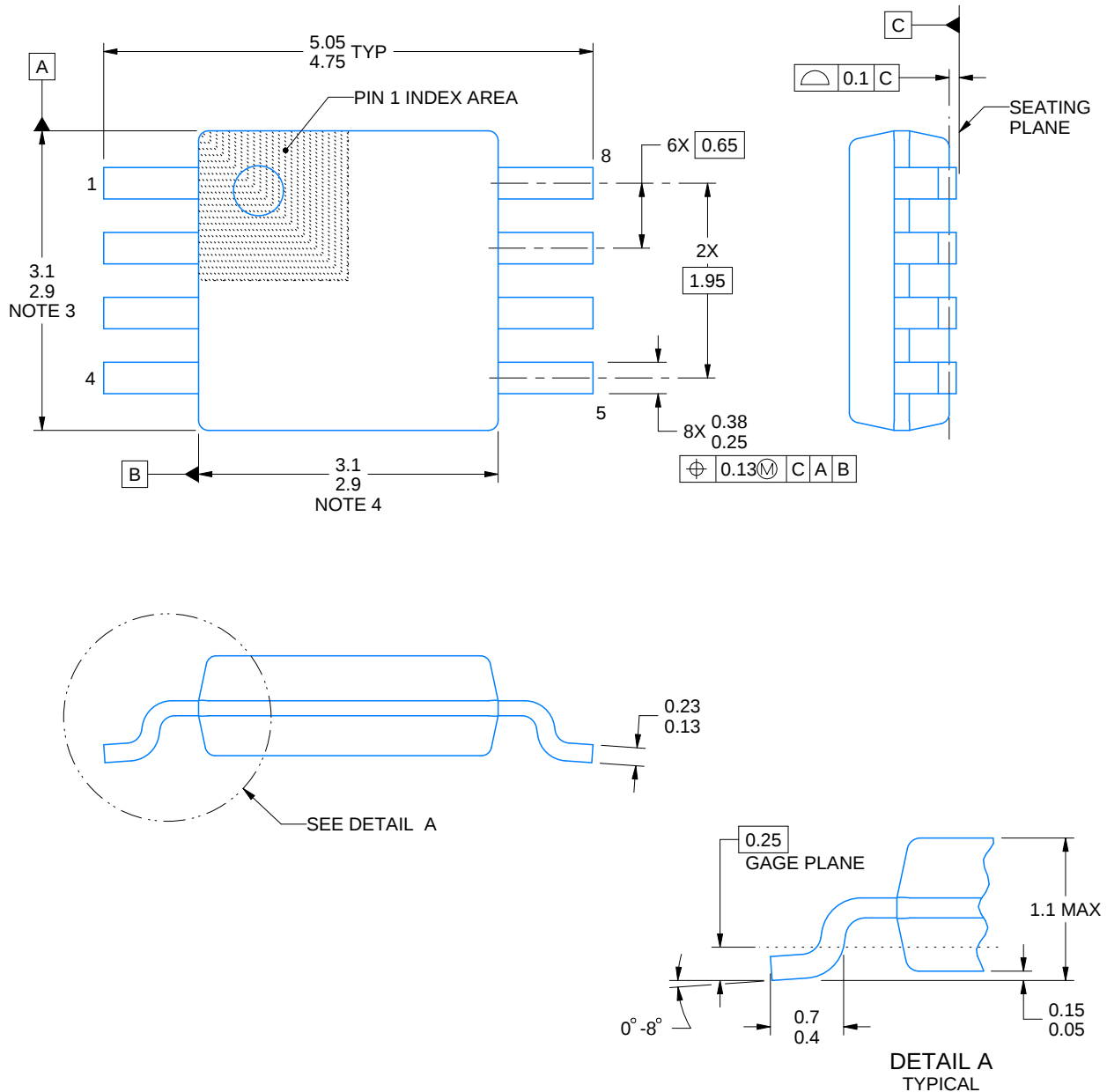
DGK0008A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES:

PowerPAD is a trademark of Texas Instruments.

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

EXAMPLE BOARD LAYOUT

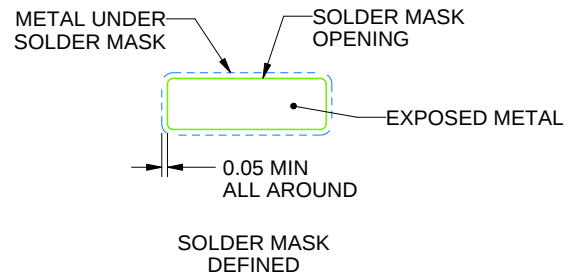
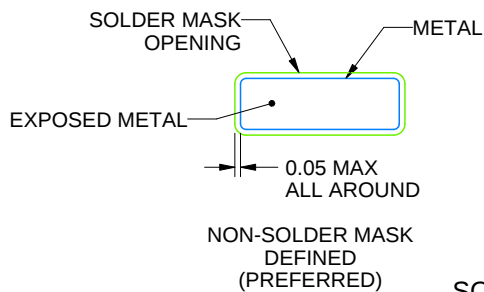
DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE: 15X



SOLDER MASK DETAILS

4214862/A 04/2023

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

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